

1. SCOPE

1.1 Scope. This drawing documents the general requirements of a high performance rail to rail, low power, operational amplifier, microcircuit, with an operating temperature range of -40°C to +125°C.

1.2 Vendor Item Drawing Administrative Control Number. The manufacturers PIN is the item of identification. The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation:

<u>V62/04651</u> Drawing number	-	<u>01</u> Device type (See 1.2.1)	<u>X</u> Case outline (See 1.2.2)	<u>E</u> Lead finish (See 1.2.3)
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1.2.1 Device type(s).

<u>Device type</u>	<u>Generic</u>	<u>Circuit function</u>
01	TLV2252	Dual, rail to rail, low power, operational amplifier
02	TLV2252A	Dual, rail to rail, low power, operational amplifier with enhanced V_{IO}
03	TLV2254	Quad, rail to rail, low power, operational amplifier
04	TLV2254A	Quad, rail to rail, low power, operational amplifier with enhanced V_{IO}

1.2.2 Case outline(s). The case outlines are as specified herein.

<u>Outline letter</u>	<u>Number of pins</u>	<u>JEDEC PUB 95</u>	<u>Package style</u>
U	8	MS-012	Plastic small outline (D-8)
X	14	MS-012	Plastic small outline (D-14)
Y	8	MS-153	Plastic small outline (PW-8)
Z	14	MS-153	Plastic small outline (PW-14)

1.2.3 Lead finishes. The lead finishes are as specified below or other lead finishes as provided by the device manufacturer:

<u>Finish designator</u>	<u>Material</u>
A	Hot solder dip
B	Tin-lead plate
C	Gold plate
D	Palladium
E	Gold flash palladium
Z	Other

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1.3 Absolute maximum ratings. 1/

Supply voltage range (V_{DD})	16 V	2/
Differential input voltage (V_{ID})	$\pm V_{DD}$	3/
Input voltage range (V_I) (any input)	$-V_{DD} - 0.3$ V to $+V_{DD}$	2/
Input current (I_I) (each input)	± 5 mA	
Output current (I_O)	± 50 mA	
Total current into $+V_{DD}$	± 50 mA	
Total current into $-V_{DD}$	± 50 mA	
Duration of short-circuit current (at or below) 25°C	Unlimited	4/
Continuous total power dissipation (P_D)	See dissipation rating table	
Operating free-air temperature range (T_A)	-40°C to +125°C	
Storage temperature range (T_{STG})	-65°C to +150°C	
Lead temperature, 1.6 mm (1/16 inch) from case for 10 seconds:		
(D and PW packages)	+260°C	

1.4 Recommended operating conditions. 5/

Supply voltage (V_{DD})	2.7 V minimum to 8 V maximum	2/
Input voltage range (V_I)	$-V_{DD}$ minimum to $+V_{DD} - 1.3$ maximum	
Common mode input voltage (V_{IC})	$-V_{DD}$ minimum to $+V_{DD} - 1.3$ maximum	
Operating free-air temperature range (T_A)	-40°C to +125°C	

Dissipation rating table

Package	$T_A \leq 25^\circ\text{C}$ power rating	Derating factor above $T_A = 25^\circ\text{C}$	$T_A = 85^\circ\text{C}$ power rating	$T_A = 125^\circ\text{C}$ power rating
D-8	725 mW	5.8 mW/°C	377 mW	145 mW
D-14	950 mW	7.6 mW/°C	494 mW	190 mW
PW-8	525 mW	4.2 mW/°C	273 mW	105 mW
PW-14	700 mW	5.6 mW/°C	364 mW	140 mW

- 1/ Stresses beyond those listed under “absolute maximum rating” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2/ All voltage values, except differential voltages, are with respect to $-V_{DD}$.
- 3/ Differential voltages are at the noninverting input with respect to the inverting input. Excessive current flows when input is brought below $-V_{DD} - 0.3$ V.
- 4/ The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.
- 5/ Use of this product beyond the manufacturers design rules or stated parameters is done at the user’s risk. The manufacturer and/or distributor maintain no responsibility or liability for product used beyond the stated limits.

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2. APPLICABLE DOCUMENTS

JEDEC PUB 95 – Registered and Standard Outlines for Semiconductor Devices

(Applications for copies should be addressed to the Electronic Industries Alliance, 2500 Wilson Boulevard, Arlington, VA 22201-3834 or online at <http://www.jedec.org>)

3. REQUIREMENTS

3.1 Marking. Parts shall be permanently and legibly marked with the manufacturer's part number as shown in 6.3 herein and as follows:

- A. Manufacturer's name, CAGE code, or logo
- B. Pin 1 identifier
- C. ESDS identification (optional)

3.2 Unit container. The unit container shall be marked with the manufacturer's part number and with items A and C (if applicable) above.

3.3 Electrical characteristics. The maximum and recommended operating conditions and electrical performance characteristics are as specified in 1.3, 1.4, and table I herein.

3.4 Design, construction, and physical dimension. The design, construction, and physical dimensions are as specified herein.

3.5 Diagrams.

3.5.1 Case outlines. The case outlines shall be as shown in 1.2.2 and figure 1.

3.5.2 Terminal connections. The terminal connections shall be as shown in figure 2.

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TABLE I. Electrical performance characteristics. 1/

Test	Symbol	Conditions $V_{DD} = 3\text{ V}$, unless otherwise specified	Temperature, $\frac{2}{T_A}$	Device type	Limits		Unit
					Min	Max	
Input offset voltage	V_{IO}	$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	01		1500	μV
				02		850	
			-40°C to +125°C	01		1750	
				02		1000	
Temperature coefficient of input offset voltage	αV_{IO}	$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C to +85°C	01,02	0.5 typical		$\mu\text{V} / ^\circ\text{C}$
Input offset voltage $\frac{3}{}$ long term drift		$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	01,02	0.003 typical		$\mu\text{V} / \text{mo}$
Input offset current	I_{IO}	$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	01,02		60	pA
			+125°C			1000	
Input bias current	I_{IB}	$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	01,02		60	pA
			+125°C			1000	
Common mode input voltage range	V_{ICR}	$ V_{IO} \leq 5\text{ mV}$, $R_S = 50\ \Omega$	25°C	01,02	0 to 2		V
			-40°C to +125°C		0 to 1.7		
High level output voltage	V_{OH}	$I_{OH} = -20\ \mu\text{A}$	25°C	01,02	2.98 typical		V
			25°C		2.9		
			-40°C to +125°C		2.8		
			25°C		2.8		
Low level output voltage	V_{OL}	$V_{IC} = 1.5\text{ V}$, $I_{OL} = 50\ \mu\text{A}$	25°C	01,02	10 typical		mV
			25°C			150	
		-40°C to +125°C			165		
		25°C			300		
		-40°C to +125°C			300		

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions $V_{DD} = 3\text{ V}$, unless otherwise specified	Temperature, $\frac{2}{T_A}$	Device type	Limits		Unit
					Min	Max	
Large signal differential voltage amplification	A_{VD}	$V_{IC} = 1.5\text{ V}$, $V_O = 1\text{ V to }2\text{ V}$, $R_L = 100\text{ k}\Omega$ referenced to 1.5 V	25°C	01,02	100		V/mV
			$-40^\circ\text{C to }+125^\circ\text{C}$		10		
		25°C	800 typical				
Differential input resistance	$r_{i(d)}$		25°C	01,02	10^{12} typical		Ω
Common mode input resistance	$r_{i(c)}$		25°C	01,02	10^{12} typical		Ω
Common mode input capacitance	$c_{i(c)}$	$f = 10\text{ kHz}$	25°C	01,02	8 typical		pF
Closed loop output impedance	z_o	$f = 25\text{ kHz}$, $A_V = 10$	25°C	01,02	220 typical		Ω
Common mode rejection ratio	CMRR	$V_{IC} = 0\text{ V to }1.7\text{ V}$, $V_O = 1.5\text{ V}$, $R_S = 50\ \Omega$	25°C	01,02	65		dB
			$-40^\circ\text{C to }+125^\circ\text{C}$		60		
Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	kSVR	$V_{DD} = 2.7\text{ V to }8\text{ V}$, no load, $V_{IC} = V_{DD} / 2$	25°C	01,02	80		dB
			$-40^\circ\text{C to }+125^\circ\text{C}$		80		
Supply current	I_{DD}	$V_O = 1.5\text{ V}$, no load	25°C	01,02		125	μA
			$-40^\circ\text{C to }+125^\circ\text{C}$			150	
Slew rate at unity gain	SR	$V_O = 0.8\text{ V to }1.4\text{ V}$, $R_L = 100\text{ k}\Omega$ referenced to 1.5 V , $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	01,02	0.07		V/ μs
			$-40^\circ\text{C to }+125^\circ\text{C}$		0.05		
Equivalent input noise voltage	V_n	$f = 10\text{ Hz}$	25°C	01,02	35 typical		nV / $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			19 typical		
Peak to peak equivalent input noise voltage	$V_{N(PP)}$	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C	01,02	0.6 typical		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			1.1 typical		

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions $V_{DD} = 3\text{ V}$, unless otherwise specified	Temperature, <u>2/</u> T_A	Device type	Limits		Unit
					Min	Max	
Equivalent input noise current	I_n		25°C	01,02	0.6 typical		fA / $\sqrt{\text{Hz}}$
Gain bandwidth product		$f = 1\text{ kHz}$, $R_L = 50\text{ k}\Omega$ referenced to 1.5 V, $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	01,02	0.187 typical		MHz
Maximum output swing bandwidth	BOM	$V_{O(PP)} = 1\text{ V}$, $A_V = 1$, $R_L = 50\text{ k}\Omega$ referenced to 1.5 V, $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	01,02	60 typical		kHz
Phase margin at unity gain	ϕ_m	$R_L = 50\text{ k}\Omega$ referenced to 1.5 V, $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	01,02	63° typical		
Gain margin		$R_L = 50\text{ k}\Omega$ referenced to 1.5 V, $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	01,02	15 typical		dB

- 1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.
- 2/ Full range is -40°C to $+125^\circ\text{C}$ for Q suffix parts.
- 3/ Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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Test	Symbol	Conditions $V_{DD} = 5\text{ V}$, unless otherwise specified	Temperature, $\underline{2/}$ T_A	Device type	Limits		Unit
					Min	Max	
Input offset voltage	V_{IO}	$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	01		1500	μV
				02		850	
			-40°C to +125°C	01		1750	
				02		1000	
Temperature coefficient of input offset voltage	αV_{IO}	$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C to +85°C	01,02	0.5 typical		$\mu\text{V} / ^\circ\text{C}$
Input offset voltage $\underline{3/}$ long term drift		$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	01,02	0.003 typical		$\mu\text{V} / \text{mo}$
Input offset current	I_{IO}	$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	01,02		60	pA
			+125°C			1000	
Input bias current	I_{IB}	$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	01,02		60	pA
			+125°C			1000	
Common mode input voltage range	V_{ICR}	$ V_{IO} \leq 5\text{ mV}$, $R_S = 50\ \Omega$	25°C	01,02	0 to 4		V
			-40°C to +125°C		0 to 3.5		
High level output voltage	V_{OH}	$I_{OH} = -20\ \mu\text{A}$	25°C	01,02	4.98 typical		V
			25°C		4.9		
			-40°C to +125°C		4.8		
			25°C		4.8		
Low level output voltage	V_{OL}	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 50\ \mu\text{A}$	25°C	01,02	0.01 typical		V
			25°C			0.15	
		-40°C to +125°C			0.15		
		$V_{IC} = 2.5\text{ V}$, $I_{OL} = 1\text{ mA}$	25°C			0.3	
			-40°C to +125°C			0.3	

See footnotes at end of table.

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Test	Symbol	Conditions $V_{DD} = 5\text{ V}$, unless otherwise specified	Temperature, $\frac{2}{T_A}$	Device type	Limits		Unit
					Min	Max	
Large signal differential voltage amplification	A_{VD}	$V_{IC} = 2.5\text{ V}$, $V_O = 1\text{ V to }4\text{ V}$,	25°C	01,02	100		V/mV
		$R_L = 100\text{ k}\Omega$ referenced to 2.5 V	$-40^\circ\text{C to }+125^\circ\text{C}$		10		
		$V_{IC} = 2.5\text{ V}$, $V_O = 1\text{ V to }4\text{ V}$, $R_L = 1\text{ M}\Omega$ referenced to 2.5 V	25°C		1700 typical		
Differential input resistance	$r_{i(d)}$		25°C	01,02	10^{12} typical		Ω
Common mode input resistance	$r_{i(c)}$		25°C	01,02	10^{12} typical		Ω
Common mode input capacitance	$c_{i(c)}$	$f = 10\text{ kHz}$	25°C	01,02	8 typical		pF
Closed loop output impedance	z_o	$f = 25\text{ kHz}$, $A_V = 10$	25°C	01,02	200 typical		Ω
Common mode rejection ratio	CMRR	$V_{IC} = 0\text{ V to }2.7\text{ V}$, $V_O = 2.5\text{ V}$,	25°C	01,02	70		dB
		$R_S = 50\ \Omega$	$-40^\circ\text{C to }+125^\circ\text{C}$		70		
Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	k_{SVR}	$V_{DD} = 4.4\text{ V to }8\text{ V}$, no load,	25°C	01,02	80		dB
		$V_{IC} = V_{DD} / 2$	$-40^\circ\text{C to }+125^\circ\text{C}$		80		
Supply current	I_{DD}	$V_O = 2.5\text{ V}$, no load	25°C	01,02		125	μA
			$-40^\circ\text{C to }+125^\circ\text{C}$			150	
Slew rate at unity gain	SR	$V_O = 1.25\text{ V to }2.75\text{ V}$, $R_L = 100\text{ k}\Omega$ referenced to 2.5 V , $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	01,02	0.07		V/ μs
			$-40^\circ\text{C to }+125^\circ\text{C}$		0.05		
Equivalent input noise voltage	V_n	$f = 10\text{ Hz}$	25°C	01,02	36 typical		nV / $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			19 typical		
Peak to peak equivalent input noise voltage	$V_{N(PP)}$	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C	01,02	0.7 typical		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			1.1 typical		

See footnotes at end of table.

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Test	Symbol	Conditions $V_{DD} = 5\text{ V}$, unless otherwise specified	Temperature, <u>2/</u> T_A	Device type	Limits		Unit
					Min	Max	
Equivalent input noise current	I_n		25°C	01,02	0.6 typical		fA / $\sqrt{\text{Hz}}$
Total harmonic distortion plus noise	THD+N	$A_V = 1$, $V_O = 0.5\text{ V to }2.5\text{ V}$, $f = 20\text{ kHz}$, $R_L = 50\text{ k}\Omega$ referenced to 2.5 V	25°C	01,02	0.2 % typical		
		$A_V = 10$, $V_O = 0.5\text{ V to }2.5\text{ V}$, $f = 20\text{ kHz}$, $R_L = 50\text{ k}\Omega$ referenced to 2.5 V			1 % typical		
Gain bandwidth product		$f = 50\text{ kHz}$, $R_L = 50\text{ k}\Omega$ referenced to 2.5 V, $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	01,02	0.2 typical		MHz
Maximum output swing bandwidth	B _{OM}	$V_{O(PP)} = 2\text{ V}$, $A_V = 1$, $R_L = 50\text{ k}\Omega$ referenced to 2.5 V, $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	01,02	30 typical		kHz
Phase margin at unity gain	ϕ_m	$R_L = 50\text{ k}\Omega$ referenced to 2.5 V, $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	01,02	63° typical		
Gain margin		$R_L = 50\text{ k}\Omega$ referenced to 2.5 V, $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	01,02	15 typical		dB

1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.

2/ Full range is -40°C to +125°C for Q suffix parts.

3/ Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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Test	Symbol	Conditions $V_{DD} = 3\text{ V}$, unless otherwise specified	Temperature, $\underline{2/}$ T_A	Device type	Limits		Unit
					Min	Max	
Input offset voltage	V_{IO}	$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	03		1500	μV
				04		850	
			-40°C to +125°C	03		1750	
				04		1000	
Temperature coefficient of input offset voltage	αV_{IO}	$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C to +85°C	03,04	0.5 typical		$\mu\text{V} / ^\circ\text{C}$
Input offset voltage $\underline{3/}$ long term drift		$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	03,04	0.003 typical		$\mu\text{V} / \text{mo}$
Input offset current	I_{IO}	$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	03,04		60	pA
			+125°C			1000	
Input bias current	I_{IB}	$\pm V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	03,04		60	pA
			+125°C			1000	
Common mode input voltage range	V_{ICR}	$ V_{IO} \leq 5\text{ mV}$, $R_S = 50\ \Omega$	25°C	03,04	0 to 2		V
			-40°C to +125°C		0 to 1.7		
High level output voltage	V_{OH}	$I_{OH} = -20\ \mu\text{A}$	25°C	03,04	2.98 typical		V
			25°C		2.9		
			-40°C to +125°C		2.8		
			25°C		2.8		
Low level output voltage	V_{OL}	$V_{IC} = 1.5\text{ V}$, $I_{OL} = 50\ \mu\text{A}$	25°C	03,04	10 typical		mV
			25°C			150	
		-40°C to +125°C			165		
		25°C			300		
		-40°C to +125°C			300		

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions $V_{DD} = 3\text{ V}$, unless otherwise specified	Temperature, $\frac{2}{T_A}$	Device type	Limits		Unit
					Min	Max	
Large signal differential voltage amplification	A_{VD}	$V_{IC} = 1.5\text{ V}$, $V_O = 1\text{ V to }2\text{ V}$,	25°C	03,04	100		V/mV
		$R_L = 100\text{ k}\Omega$ referenced to 1.5 V	$-40^\circ\text{C to }+125^\circ\text{C}$		10		
		$V_{IC} = 1.5\text{ V}$, $V_O = 1\text{ V to }2\text{ V}$, $R_L = 1\text{ M}\Omega$ referenced to 1.5 V	25°C		800 typical		
Differential input resistance	$r_{i(d)}$		25°C	03,04	10^{12} typical		Ω
Common mode input resistance	$r_{i(c)}$		25°C	03,04	10^{12} typical		Ω
Common mode input capacitance	$c_{i(c)}$	$f = 10\text{ kHz}$	25°C	03,04	8 typical		pF
Closed loop output impedance	z_o	$f = 25\text{ kHz}$, $A_V = 10$	25°C	03,04	220 typical		Ω
Common mode rejection ratio	CMRR	$V_{IC} = 0\text{ V to }1.7\text{ V}$, $V_O = 1.5\text{ V}$,	25°C	03,04	65		dB
		$R_S = 50\ \Omega$	$-40^\circ\text{C to }+125^\circ\text{C}$		60		
Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	k_{SVR}	$V_{DD} = 2.7\text{ V to }8\text{ V}$, no load,	25°C	03,04	80		dB
		$V_{IC} = V_{DD} / 2$	$-40^\circ\text{C to }+125^\circ\text{C}$		80		
Supply current (four amplifiers)	I_{DD}	$V_O = 1.5\text{ V}$, no load	25°C	03,04		250	μA
			$-40^\circ\text{C to }+125^\circ\text{C}$			300	
Slew rate at unity gain	SR	$V_O = 0.5\text{ V to }1.7\text{ V}$, $R_L = 100\text{ k}\Omega$ referenced to 1.5 V , $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	03,04	0.07		V/ μs
			$-40^\circ\text{C to }+125^\circ\text{C}$		0.05		
Equivalent input noise voltage	V_n	$f = 10\text{ Hz}$	25°C	03,04	35 typical		nV / $\sqrt{\text{Hz}}$
					$f = 1\text{ kHz}$	19 typical	
Peak to peak equivalent input noise voltage	$V_{N(PP)}$	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C	03,04	0.6 typical		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			1.1 typical		

See footnotes at end of table.

DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO	SIZE A	CODE IDENT NO. 16236	DWG NO. V62/04651
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TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions $V_{DD} = 3\text{ V}$, unless otherwise specified	Temperature, <u>2/</u> T_A	Device type	Limits		Unit
					Min	Max	
Equivalent input noise current	I_n		25°C	03,04	0.6 typical		fA / $\sqrt{\text{Hz}}$
Gain bandwidth product		$f = 1\text{ kHz}$, $R_L = 50\text{ k}\Omega$ referenced to 1.5 V, $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	03,04	0.187 typical		MHz
Maximum output swing bandwidth	BOM	$V_{O(PP)} = 1\text{ V}$, $A_V = 1$, $R_L = 50\text{ k}\Omega$ referenced to 1.5 V, $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	03,04	60 typical		kHz
Phase margin at unity gain	ϕ_m	$R_L = 50\text{ k}\Omega$ referenced to 1.5 V, $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	03,04	63° typical		
Gain margin		$R_L = 50\text{ k}\Omega$ referenced to 1.5 V, $C_L = 100\text{ pF}$ referenced to 1.5 V	25°C	03,04	15 typical		dB

- 1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.
- 2/ Full range is -40°C to +125°C for Q suffix parts.
- 3/ Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions $V_{DD} = 5\text{ V}$, unless otherwise specified	Temperature, $\underline{2/}$ T_A	Device type	Limits		Unit
					Min	Max	
Input offset voltage	V_{IO}	$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	03		1500	μV
				04		850	
			-40°C to +125°C	03		1750	
				04		1000	
Temperature coefficient of input offset voltage	αV_{IO}	$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C to +85°C	03,04	0.5 typical		$\mu\text{V} / ^\circ\text{C}$
Input offset voltage $\underline{3/}$ long term drift		$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	03,04	0.003 typical		$\mu\text{V} / \text{mo}$
Input offset current	I_{IO}	$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	03,04		60	pA
			+125°C			1000	
Input bias current	I_{IB}	$\pm V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C	03,04		60	pA
			+125°C			1000	
Common mode input voltage range	V_{ICR}	$ V_{IO} \leq 5\text{ mV}$, $R_S = 50\ \Omega$	25°C	03,04	0 to 4		V
			-40°C to +125°C		0 to 3.5		
High level output voltage	V_{OH}	$I_{OH} = -20\ \mu\text{A}$	25°C	03,04	4.98 typical		V
			25°C		4.9		
			-40°C to +125°C		4.8		
			25°C		4.8		
Low level output voltage	V_{OL}	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 50\ \mu\text{A}$	25°C	03,04	0.01 typical		V
			25°C			0.15	
		-40°C to +125°C			0.15		
		$V_{IC} = 2.5\text{ V}$, $I_{OL} = 1\text{ mA}$	25°C			0.3	
			-40°C to +125°C			0.3	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions $V_{DD} = 5\text{ V}$, unless otherwise specified	Temperature, $\frac{2}{T_A}$	Device type	Limits		Unit
					Min	Max	
Large signal differential voltage amplification	A_{VD}	$V_{IC} = 2.5\text{ V}$, $V_O = 1\text{ V to }4\text{ V}$,	25°C	03,04	100		V/mV
		$R_L = 100\text{ k}\Omega$ referenced to 2.5 V	$-40^\circ\text{C to }+125^\circ\text{C}$		10		
		$V_{IC} = 2.5\text{ V}$, $V_O = 1\text{ V to }4\text{ V}$, $R_L = 1\text{ M}\Omega$ referenced to 2.5 V	25°C		1700 typical		
Differential input resistance	$r_{i(d)}$		25°C	03,04	10^{12} typical		Ω
Common mode input resistance	$r_{i(c)}$		25°C	03,04	10^{12} typical		Ω
Common mode input capacitance	$c_{i(c)}$	$f = 10\text{ kHz}$	25°C	03,04	8 typical		pF
Closed loop output impedance	z_o	$f = 25\text{ kHz}$, $A_V = 10$	25°C	03,04	200 typical		Ω
Common mode rejection ratio	CMRR	$V_{IC} = 0\text{ V to }2.7\text{ V}$, $V_O = 2.5\text{ V}$,	25°C	03,04	70		dB
		$R_S = 50\ \Omega$	$-40^\circ\text{C to }+125^\circ\text{C}$		70		
Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	k_{SVR}	$V_{DD} = 4.4\text{ V to }8\text{ V}$, no load,	25°C	03,04	80		dB
		$V_{IC} = V_{DD} / 2$	$-40^\circ\text{C to }+125^\circ\text{C}$		80		
Supply current (four amplifiers)	I_{DD}	$V_O = 2.5\text{ V}$, no load	25°C	03,04		250	μA
			$-40^\circ\text{C to }+125^\circ\text{C}$			300	
Slew rate at unity gain	SR	$V_O = 0.5\text{ V to }3.5\text{ V}$, $R_L = 100\text{ k}\Omega$ referenced to 2.5 V , $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	03,04	0.07		V/ μs
			$-40^\circ\text{C to }+125^\circ\text{C}$		0.05		
Equivalent input noise voltage	V_n	$f = 10\text{ Hz}$	25°C	03,04	36 typical		nV / $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			19 typical		
Peak to peak equivalent input noise voltage	$V_{N(PP)}$	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C	03,04	0.7 typical		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			1.1 typical		

See footnotes at end of table.

DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO	SIZE A	CODE IDENT NO. 16236	DWG NO. V62/04651
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TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions $V_{DD} = 5\text{ V}$, unless otherwise specified	Temperature, <u>2/</u> T_A	Device type	Limits		Unit
					Min	Max	
Equivalent input noise current	I_n		25°C	03,04	0.6 typical		fA / $\sqrt{\text{Hz}}$
Total harmonic distortion plus noise	THD+N	$A_V = 1$, $V_O = 0.5\text{ V to }2.5\text{ V}$, $f = 20\text{ kHz}$, $R_L = 50\text{ k}\Omega$ referenced to 2.5 V	25°C	03,04	0.2 % typical		
		$A_V = 10$, $V_O = 0.5\text{ V to }2.5\text{ V}$, $f = 20\text{ kHz}$, $R_L = 50\text{ k}\Omega$ referenced to 2.5 V			1 % typical		
Gain bandwidth product		$f = 50\text{ kHz}$, $R_L = 50\text{ k}\Omega$ referenced to 2.5 V, $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	03,04	0.2 typical		MHz
Maximum output swing bandwidth	B _{OM}	$V_{O(PP)} = 2\text{ V}$, $A_V = 1$, $R_L = 50\text{ k}\Omega$ referenced to 2.5 V, $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	03,04	30 typical		kHz
Phase margin at unity gain	ϕ_m	$R_L = 50\text{ k}\Omega$ referenced to 2.5 V, $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	03,04	63° typical		
Gain margin		$R_L = 50\text{ k}\Omega$ referenced to 2.5 V, $C_L = 100\text{ pF}$ referenced to 2.5 V	25°C	03,04	15 typical		dB

1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.

2/ Full range is -40°C to +125°C for Q suffix parts.

3/ Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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Case U

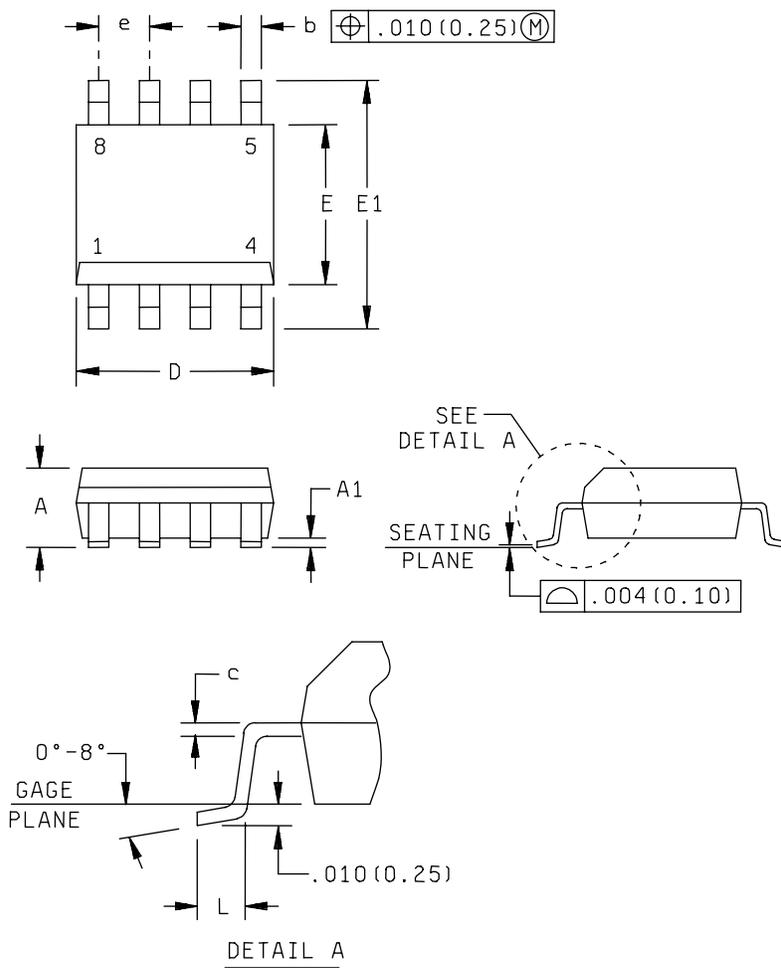


FIGURE 1. Case outlines.

<p>DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO</p>	<p>SIZE A</p>	<p>CODE IDENT NO. 16236</p>	<p>DWG NO. V62/04651</p>
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Case U - Continued

Symbol	Dimensions			
	Inches		Millimeters	
	Min	Max	Min	Max
A		.069		1.75
A1	.004	.010	0.10	0.25
b	.014	.020	0.35	0.51
c		.008 NOM		0.20 NOM
D	.189	.197	4.80	5.00
E	.150	.157	3.81	4.00
E1	.228	.244	5.80	6.20
e		.050 BSC		1.27 BSC
L	.016	.044	0.40	1.12

NOTES:

1. All linear dimensions are in inches (millimeters).
2. This case outline is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion, not to exceed .006 inch (0.15 mm).
4. Fall within JEDEC MS-012.

FIGURE 1. Case outlines - Continued.

DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO	SIZE A	CODE IDENT NO. 16236	DWG NO. V62/04651
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Case X

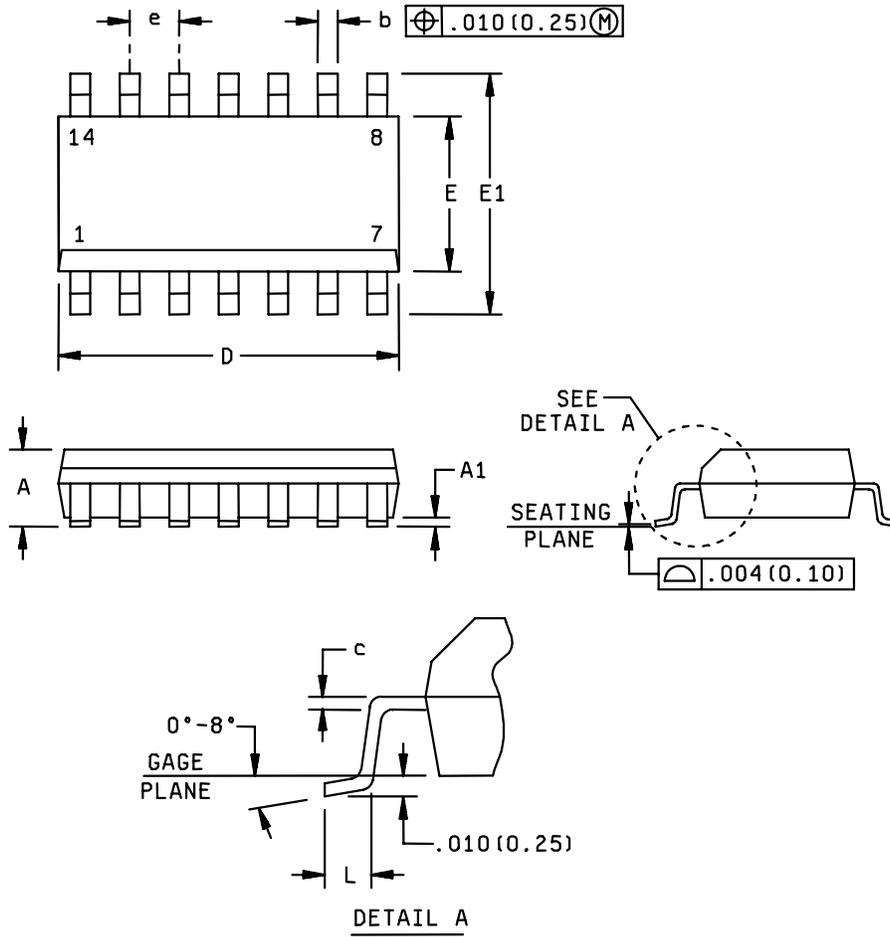


FIGURE 1. Case outlines –Continued.

<p>DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO</p>	<p>SIZE A</p>	<p>CODE IDENT NO. 16236</p>	<p>DWG NO. V62/04651</p>
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Case X - Continued

Symbol	Dimensions			
	Inches		Millimeters	
	Min	Max	Min	Max
A		.069		1.75
A1	.004	.010	0.10	0.25
b	.014	.020	0.35	0.51
c		.008 NOM		0.20 NOM
D	.337	.344	8.55	8.75
E	.150	.157	3.81	4.00
E1	.228	.244	5.80	6.20
e		.050 BSC		1.27 BSC
L	.016	.044	0.40	1.12

NOTES:

1. All linear dimensions are in inches (millimeters).
2. This case outline is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion, not to exceed .006 inch (0.15 mm).
4. Fall within JEDEC MS-012.

FIGURE 1. Case outlines - Continued.

DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO	SIZE A	CODE IDENT NO. 16236	DWG NO. V62/04651
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Case Y

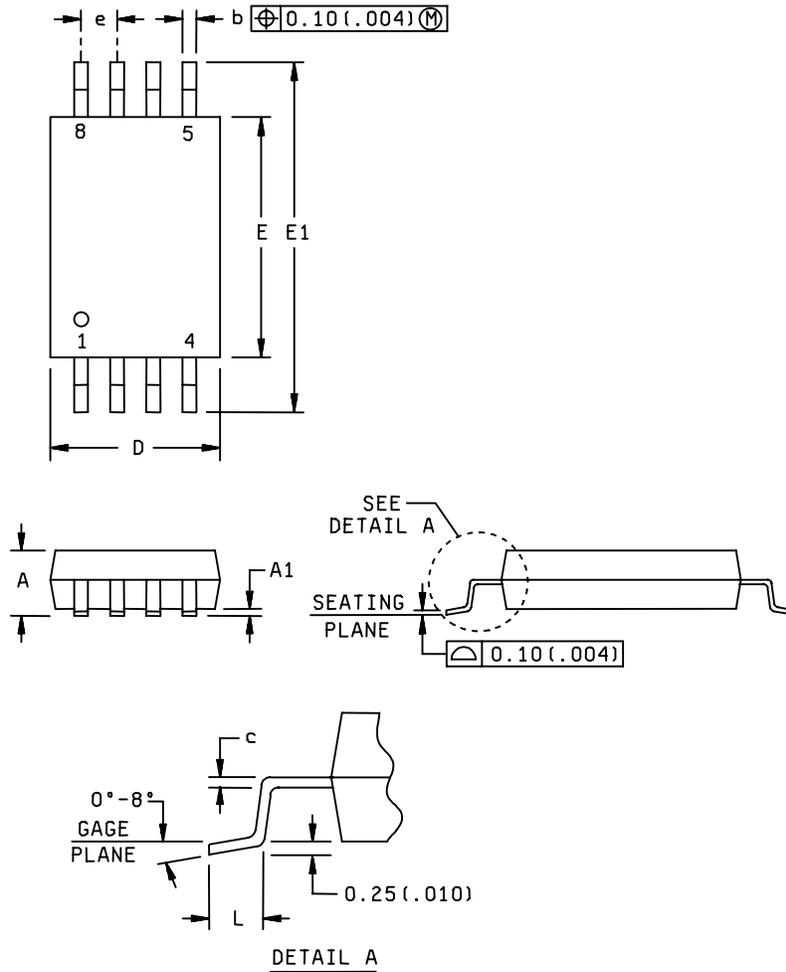


FIGURE 1. Case outlines - Continued.

<p>DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO</p>	<p>SIZE A</p>	<p>CODE IDENT NO. 16236</p>	<p>DWG NO. V62/04651</p>
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Case Y - Continued

Symbol	Dimensions			
	Millimeters		Inches	
	Min	Max	Min	Max
A		1.20		.047
A1	0.05	0.15	.002	.006
b	0.19	0.30	.007	.012
c		0.15 NOM		.006 NOM
D	2.90	3.10	.114	.122
E	4.30	4.50	.169	.177
E1	6.20	6.60	.244	.260
e		0.65 BSC		.026 BSC
L	0.50	0.75	.020	.030

NOTES:

1. All linear dimensions are in millimeters (inches).
2. This case outline is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion, not to exceed 0.15 millimeter (0.006 inch).
4. Fall within JEDEC MO-153.

FIGURE 1. Case outlines - Continued.

DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO	SIZE A	CODE IDENT NO. 16236	DWG NO. V62/04651
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Case Z

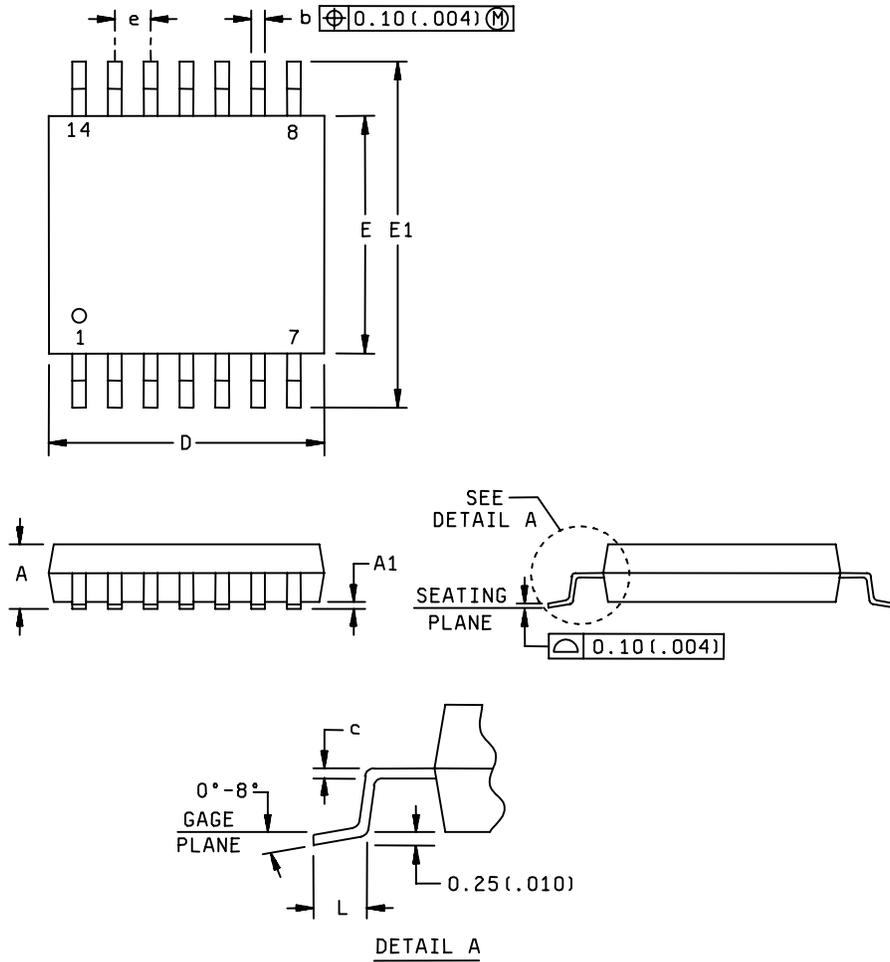


FIGURE 1. Case outlines - Continued.

<p>DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO</p>	<p>SIZE A</p>	<p>CODE IDENT NO. 16236</p>	<p>DWG NO. V62/04651</p>
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Case Z - Continued

Symbol	Dimensions			
	Millimeters		Inches	
	Min	Max	Min	Max
A		1.20		.047
A1	0.05	0.15	.002	.006
b	0.19	0.30	.007	.012
c		0.15 NOM		.006 NOM
D	4.90	5.10	.193	.201
E	4.30	4.50	.169	.177
E1	6.20	6.60	.244	.260
e		0.65 BSC		.026 BSC
L	0.50	0.75	.020	.030

NOTES:

1. All linear dimensions are in millimeters (inches).
2. This case outline is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion, not to exceed 0.15 millimeter (0.006 inch).
4. Fall within JEDEC MO-153.

FIGURE 1. Case outlines - Continued.

DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO	SIZE A	CODE IDENT NO. 16236	DWG NO. V62/04651
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Device types	01 and 02	03 and 04
Case outlines	U and Y	X and Z
Terminal number	Terminal symbol	
1	OUT1	OUT1
2	-IN1	-IN1
3	+IN1	+IN1
4	-V _{DD} / GND	+V _{DD}
5	+IN2	+IN2
6	-IN2	-IN2
7	OUT2	OUT2
8	+V _{DD}	OUT3
9	---	-IN3
10	---	+IN3
11	---	-V _{DD} / GND
12	---	+IN4
13	---	-IN4
14	---	OUT4

FIGURE 2. Terminal connections.

DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO	SIZE A	CODE IDENT NO. 16236	DWG NO. V62/04651
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4. VERIFICATION

4.1 Product assurance requirements. The manufacturer is responsible for performing all inspection and test requirements as indicated in their internal documentation. Such procedures should include proper handling of electrostatic sensitive devices, classification, packaging, and labeling of moisture sensitive devices, as applicable.

5. PREPARATION FOR DELIVERY

5.1 Packaging. Preservation, packaging, labeling, and marking shall be in accordance with the manufacturer's standard commercial practices for electrostatic discharge sensitive devices.

6. NOTES

6.1 ESDS. Devices are electrostatic discharge sensitive and are classified as ESDS class 1 minimum.

6.2 Configuration control. The data contained herein is based on the salient characteristics of the device manufacturer's data book. The device manufacturer reserves the right to make changes without notice. This drawing will be modified as changes are provided.

6.3 Suggested source(s) of supply. Identification of the suggested source(s) of supply herein is not to be construed as a guarantee of present or continued availability as a source of supply for the item.

Vendor item drawing administrative control number <u>1/</u>	V _{IO} max at 25°C	Device manufacturer CAGE code	Package		Vendor part number	Top side marking
V62/04651-01UE	1500 μV	01295	SOIC (D)	Tape and reel	TLV2252QDREP	2252EP
V62/04651-01YE		01295	TSSOP (PW)	Tape and reel	TLV2252QPWREP <u>2/</u>	
V62/04651-02UE	850 μV	01295	SOIC (D)	Tape and reel	TLV2252AQDREP	2252AE
V62/04651-02YE		01295	TSSOP (PW)	Tape and reel	TLV2252AQPWREP <u>2/</u>	
V62/04651-03XE	1500 μV	01295	SOIC (D)	Tape and reel	TLV2254QDREP	TLV2254EP
V62/04651-03ZE		01295	TSSOP (PW)	Tape and reel	TLV2254QPWREP <u>2/</u>	
V62/04651-04XE	850 μV	01295	SOIC (D)	Tape and reel	TLV2254AQDREP	TLV2254AEP
V62/04651-04ZE		01295	TSSOP (PW)	Tape and reel	TLV2254AQPWREP <u>2/</u>	

1/ The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation.

2/ This part is not available as of the release date of this drawing.

CAGE code

01295

Source of supply

Texas Instruments, Inc.
 Semiconductor Group
 8505 Forest Lane
 P.O. Box 660199
 Dallas, TX 75243
 Point of contact: U.S. Highway 75 South
 P.O. Box 84, M/S 853
 Sherman, TX 75090-9493

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